

Vishay Siliconix

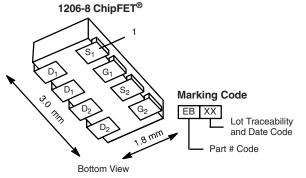
Complementary 20 V (D-S) MOSFET

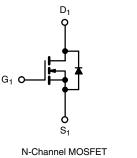
PRODUCT SUMMARY							
	V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	Q _g (Typ.)			
N-Channel	20	0.075 at V _{GS} = 4.5 V	4.2	Λ			
		0.134 at V _{GS} = 2.5 V	3.1	4			
P-Channel	- 20	0.155 at V _{GS} = - 4.5 V	- 2.9	3			
		0.260 at V _{GS} = - 2.5 V	- 2.2	3			

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC









 G_2

S2

Ordering Information: Si5513DC-T1-E3 (Lead (Pb)-free) Si5513DC-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	N-Channel		P-Channel		
			5 s	Steady State	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	20		- 20		V
Gate-Source Voltage		V _{GS}	± 12				V
	T _A = 25 °C	- I _D	4.2	3.1	- 2.9	- 2.1	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		3.0	2.2	- 2.1	- 1.5	
Pulsed Drain Current		I _{DM}	10 - 10		- 10	A	
Continuous Source Current (Diode Conduction) ^a		ا _S	1.8	0.9	- 1.8	- 0.9	
	T _A = 25 °C	P _D	2.1	1.1	2.1	1.1	w
Maximum Power Dissipation ^a	T _A = 85 °C		1.1	0.6	1.1	0.6	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150				
Soldering Recommendations (Peak Temperature) ^{b, c}			260				°C

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^a	t ≤ 5 s	R _{thJA}	50	60			
	Steady State		90	110	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	30	40			

Notes:

a. Surface mounted on 1" x 1" FR4 board.

b. See reliability manual for profile. The ChipFET is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

Si5513DC

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	•	•					
Cata Threshold Valtage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	N-Ch	0.6		1.5	v
Gate Threshold Voltage		$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	P-Ch	- 0.6		- 1.5	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 12 V	N-Ch			± 100	nA
			P-Ch			± 100	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$	N-Ch			1	μA
		$V_{DS} = -20 V, V_{GS} = 0 V$	P-Ch			- 1	
	'DSS	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$ N-Ch				5	μΛ
		V_{DS} = - 20 V, V_{GS} = 0 V, T_{J} = 70 °C	P-Ch			- 5	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5$ V, $V_{GS} = 4.5$ V	N-Ch	10			А
		$V_{DS}{\leq}$ - 5 V, $V_{GS}{=}$ - 4.5 V	P-Ch	- 10			
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 3.1 A	N-Ch		0.065	0.075	
		V _{GS} = - 4.5 V, I _D = - 2.1 A	P-Ch		0.130	0.155	Ω
		$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 2.3 \text{ A}$	N-Ch		0.115	0.134	
		V _{GS} = - 2.5 V, I _D = - 1.7 A	P-Ch		0.215	0.260	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 3.1 A	N-Ch		8		_
		V _{DS} = - 10 V, I _D = - 2.1 A	P-Ch		5		S
	V _{SD}	$I_{\rm S} = 0.9$ A, $V_{\rm GS} = 0$ V	N-Ch		0.8	1.2	
Diode Forward Voltage ^a		I _S = - 0.9 A, V _{GS} = 0 V	P-Ch		- 0.8	- 1.2	V
Dynamic ^b		· · · · · ·					
Total Gate Charge	Qg		N-Ch		4	6	
Total Gate Charge	Qg	N-Channel $V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 3.1 \text{ A}$	P-Ch		3	6	
Gate-Source Charge	Q _{gs}	IN-C			0.6		nC
g-		P-Channel	P-Ch		0.9		-
Gate-Drain Charge	Q _{gd}	V_{DS} = - 10 V, V_{GS} = - 4.5 V, I_D = - 2.1 A	N-Ch		1.3		
			P-Ch N-Ch		0.6 12	18	
Turn-On Delay Time	t _{d(on)}	N-Channel	P-Ch		12	20	
		V_{DD} = 10 V, R_L = 10 Ω	N-Ch		35	55	
Rise Time		$I_D \cong 1$ A, V_{GEN} = 4.5 V, R_g = 6 Ω	P-Ch		35	55	
	t _{d(off)}	P-Channel	N-Ch		19	30	-
Turn-Off Delay Time		$V_{DD} = -10 \text{ V}, \text{ R}_{L} = 10 \Omega$	P-Ch		25	40	ns
Fall Time	t _f	$I_D \cong$ - 1 A, V_{GEN} = - 4.5 V, R_g = 6 Ω	N-Ch		9	15	
	Ч	Ŭ	P-Ch		25	40	
Source-Drain Reverse Recovery Time	t	I _F = 0.9 A, dl/dt = 100 A/μs	N-Ch		40	80	
	t _{rr}	I _F = - 0.9 A, dl/dt = 100 A/μs	P-Ch		40	80	

Notes:

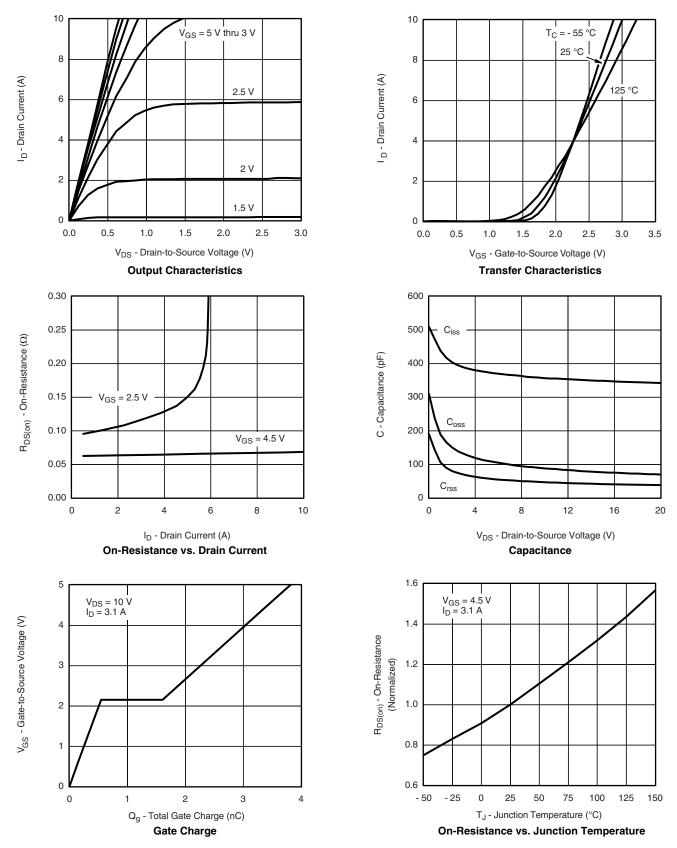
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



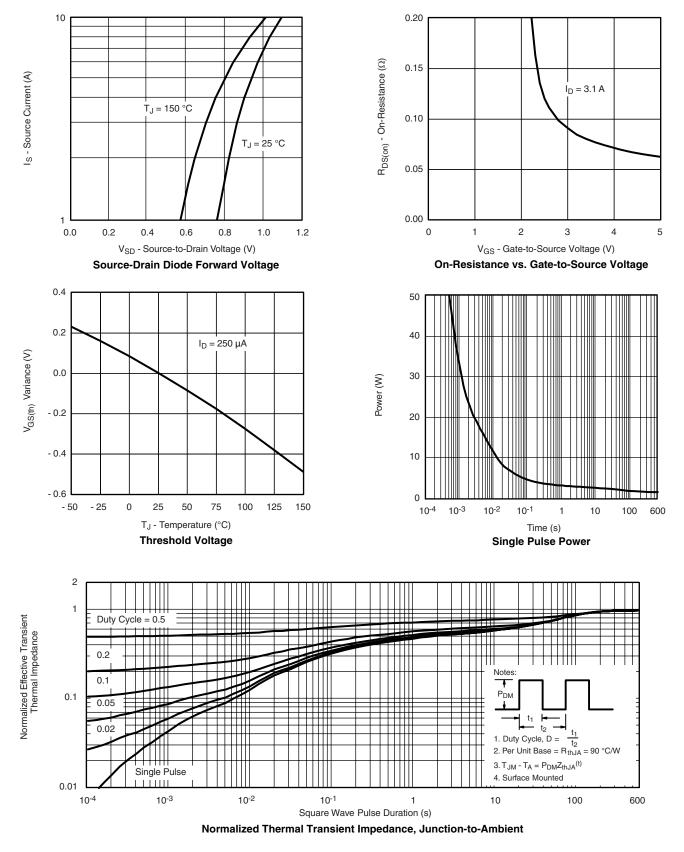
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Si5513DC



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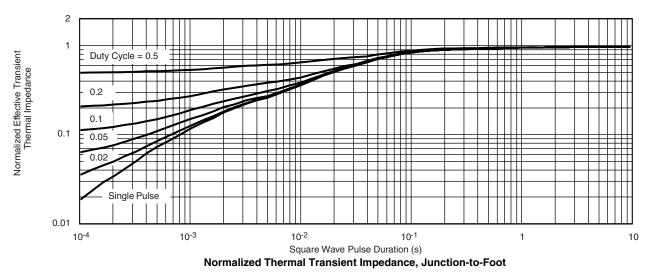
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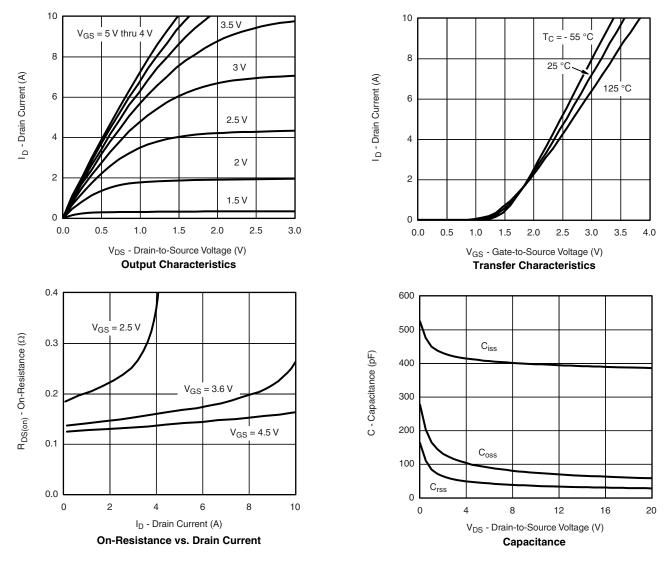
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P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



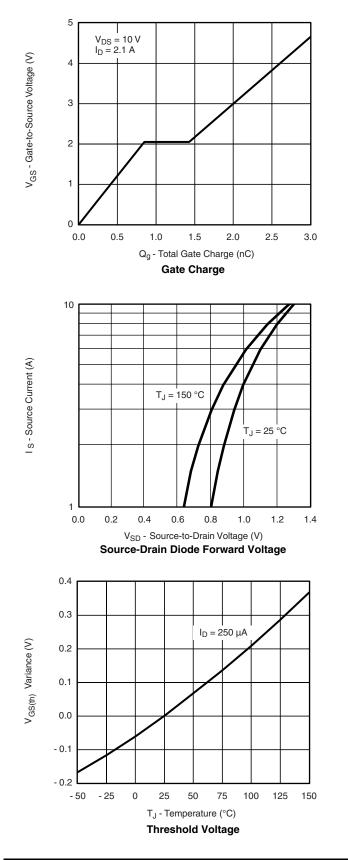
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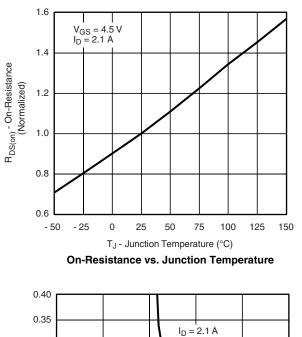
Si5513DC

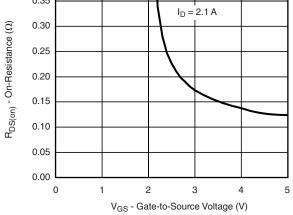


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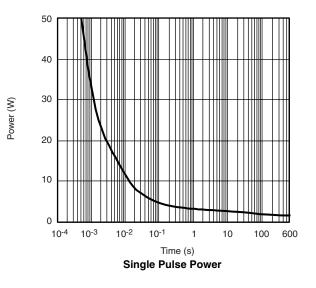
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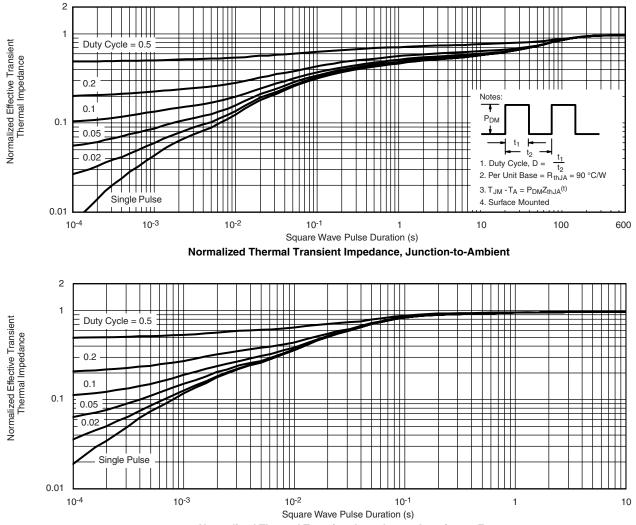
On-Resistance vs. Gate-to-Source Voltage



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Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71186.

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